

v00.1115

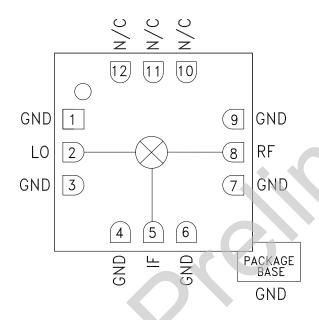
GAAS MMIC FUNDAMENTAL MIXER, 16 - 30 GHz

Typical Applications The

HMC292ALC3B is ideal for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios & VSAT
- Test Equipment & Sensors
- Military End-Use

Functional Diagram



Features

Passive: No DC Bias Required

Input IP3: +20 dBm LO/RF Isolation: 40 dB

Wide IF Bandwidth: DC - 8 GHz

Robust 1000V ESD, Class 1C

12 Lead Ceramic 3x3 mm SMT Package: 9mm²

General Description

The HMC292ALC3B is a general purpose passive double balanced mixer in a leadless RoHS-Compliant SMT package that can be used as an upconverter or downconverter between 16 and 30 GHz. This mixer requires no external components or matching circuitry. The HMC292ALC3B provides excellent LO to RF and LO to IF suppression due to optimized balun structures. The mixer operates with LO drive levels above +9 dBm. The HMC292ALC3B eliminates the need for wire bonding, allowing use of surface mount manufacturing techniques.

Electrical Specifications, $T_A = +25^{\circ}$ C, IF= 1 GHz, LO= +13 dBm*

| Parameter | Min. | Тур. | Max. | Min. | Тур. | Max. | Units |
|-------------------------------|------|---------|------|------|---------|------|-------|
| Frequency Range, RF & LO | | 16 - 26 | | | 26 - 30 | | GHz |
| Frequency Range, IF | | DC - 8 | | | DC - 8 | | GHz |
| Conversion Loss | | 8 | 11 | | 9.5 | 12.5 | dB |
| Noise Figure (SSB) | | 8 | 11 | | 9.5 | 12.5 | dB |
| LO to RF Isolation | 34 | 40 | | 32 | 40 | | dB |
| LO to IF Isolation | 24 | 32 | | 28 | 34 | | dB |
| RF to IF Isolation | 14 | 25 | | 24 | 30 | | dB |
| IP3 (Input) | 15 | 18 | | 17 | 21 | | dBm |
| IP2 (Input) | | 48 | | | 50 | | dBm |
| 1 dB Gain Compression (Input) | 8 | 13 | | 8 | 14 | | dBm |

^{*}Unless otherwise noted, all measurements performed as downconverter, IF= 1 GHz.



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Absolute Maximum Ratings

| RF / IF Input | +13 dBm |
|---|----------------|
| LO Drive | +27 dBm |
| Channel Temperature | 150 °C |
| Continuous Pdiss (Ta = 85 °C) (derate 4.0 mW/°C above 85 °C) | 260 mW |
| Thermal Resistance (junction to ground paddle) | 250 °C/W |
| Storage Temperature | -65 to +150 °C |
| Operating Temperature | -40 to +85 °C |
| ESD Sensitivity (HBM) | Class 1C |

MxN Spurious Outputs

| | nLO | | | | | | | | | |
|-----|-----|----|----|----|-----|--|--|--|--|--|
| mRF | 0 | 1 | 2 | 3 | 4 | | | | | |
| 0 | xx | 13 | 47 | xx | xx | | | | | |
| 1 | 23 | 0 | 50 | 51 | xx | | | | | |
| 2 | 87 | 72 | 64 | 72 | 89 | | | | | |
| 3 | xx | 89 | 88 | 73 | 92 | | | | | |
| 4 | xx | xx | 86 | 95 | 104 | | | | | |
| | | | | | | | | | | |

RF = 22 GHz @ -10 dBm

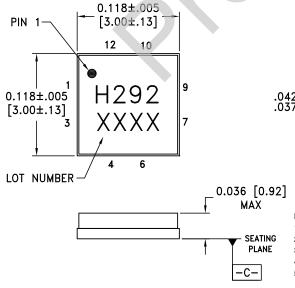
LO = 21 GHz @ +13 dBm

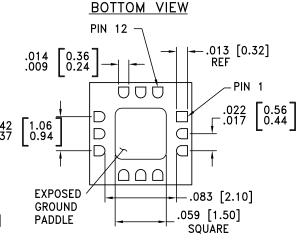
All values in dBc below the IF output power level.



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Outline Drawing





IOTES:

- 1. PACKAGE BODY MATERIAL: ALUMINA.
- 2. LEAD AND GROUND PADDLE PLATING: GOLD FLASH OVER NICKEL.
- 3. DIMENSIONS ARE IN INCHES (MILLIMETERS).
- 4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- 5. CHARACTERS TO BE HELVETICA MEDIUM, .025 HIGH, BLACK INK, OR LASER MARK LOCATED APPROX. AS SHOWN.
- 6. PACKAGE WARP SHALL NOT EXCEED 0.05MM DATUM C -
- 7. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.